



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Marra

Serial No.: 09/917,573

Filed: July 27, 2001

For: **Active Element Bias Circuit for RF Power Transistor Input**

Attorney Docket No: 4740-075

Patent Pending

Examiner: Michael B. Shingleton

Group Art Unit: 2817

San Diego, CA
December 18, 2002

Commissioner for Patents
Box Non-Fee Amendment
Washington, D.C. 20231

AMENDMENT

Dear Sir:

This is a response to the Office Action mailed on September 24, 2002, setting a period of response expiring on December 24, 2002. Please amend the above-identified application as follows:

IN THE SPECIFICATION

Please amend the paragraph beginning on page 9, line 3 as shown (marked-up version appears in the attachment entitled "AMENDMENTS WITH VERSION MARKINGS"):

The op amp 155 preferably has high internal impedance at its two input terminals so that negligible current flows into the negative input terminal from the voltage bias source 135. That way, almost all of the current passing through resistor 160 from the voltage bias source 135 also flows through resistors 165 and 130. In addition, the op amp 155, preferably, has a relative low

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Conrad